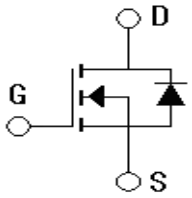
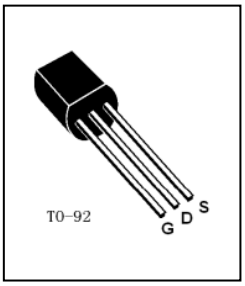
JCS2N60C

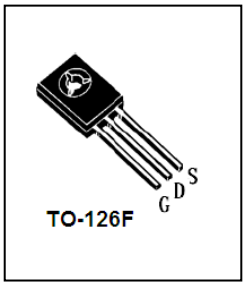
主要参数 MAIN CHARACTERISTICS

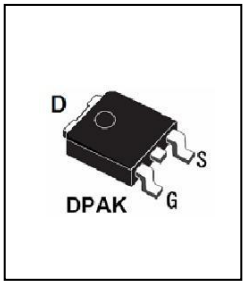
I_D	2.0 A
V_{DSS}	600 V
Rdson-max （Vgs=10V）	5.0 Ω
Qg-typ	8.1 nC

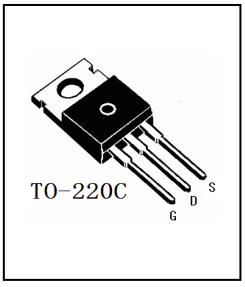
封装 **Package**

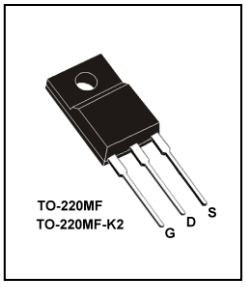












用途

- 高频开关电源
- 电子镇流器
- LED 电源

APPLICATIONS

- High efficiency switch mode power supplies
- Electronic lamp ballasts based on half bridge
- LED power supplie

产品特性

- 低栅极电荷
- 低C_{rss} (典型值 3.1pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

FEATURES

- Low gate charge
- Low C_{rss} (typical 3.1pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

订货信息 ORDER MESSAGE

订货型号 Order codes				印记 Marking	封装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
N/A	N/A	JCS2N60TC-T-A	JCS2N60TC-T-AR	JCS2N60T	TO-92
JCS2N60MFC-MF-B	JCS2N60MFC-MF-BR	N/A	N/A	JCS2N60MF	TO-126F
JCS2N60VC-V-B	JCS2N60VC-V-BR	N/A	N/A	JCS2N60V	IPAK
JCS2N60RC-R-B	JCS2N60RC-R-BR	JCS2N60RC-R-A	JCS2N60RC-R-AR	JCS2N60R	DPAK
JCS2N60CC-C-B	JCS2N60CC-C-BR	N/A	N/A	JCS2N60C	TO-220C
JCS2N60FC-F-B	JCS2N60FC-F-BR	N/A	N/A	JCS2N60F	TO-220MF
JCS2N60FC-F2-B	JCS2N60FC-F2-BR	N/A	N/A	JCS2N60F	TO-220MF-K2

绝对最大额定值 ABSOLUTE RATINGS (Tc=25℃)

项 目 Parameter	符 号 Symbol	数 值 Value				单位 Unit
		JCS2N60 VC/RC/MFC	JCS2N60 CC	JCS2N60 FC	JCS2N60 TC	
最高漏极－源极直流电压 Drain-Source Voltage	V_{DSS}	600				V
连续漏极电流 Drain Current-continuous	I_D T=25℃	1.9	2.0	2.0*		A
	T=100℃	1.1	1.3	1.3*		A
最大脉冲漏极电流（注 1） Drain Current – pulse （note 1）	I_{DM}	8.0		8.0*		A
最高栅源电压 Gate-Source Voltage	V_{GSS}	±30				V
单脉冲雪崩能量（注 2） Single Pulsed Avalanche Energy（note 2）	E_{AS}	240				mJ
雪崩电流（注 1） Avalanche Current （note 1）	I_{AR}	1.9				A
重复雪崩能量（注 1） Repetitive Avalanche Current （note 1）	E_{AR}	4.2				mJ
二极管反向恢复最大电压变化速率（注 3） Peak Diode Recovery dv/dt （note 3）	dv/dt	4.6				V/ns
耗散功率 Power Dissipation	P_D T_C=25℃	44	54	43.9	4	W
	-Derate above 25℃	0.35	0.43	0.35	0.025	W/℃
最高结温及存储温度 Operating and Storage Temperature Range	T_J，T_{STG}	-55～+150				℃

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature

电特性 ELECTRICAL CHARACTERISTICS

项　　目 Parameter	符　号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单　位 Units
关态特性 Off –Characteristics						
漏－源击穿电压 Drain-Source Voltage	BV_{DSS}	I_D=250μA, V_{GS}=0V	600	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	I_D=1mA, referenced to 25℃	-	0.6	-	V/℃
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=600V,V_{GS}=0V, T_C=25℃	-	-	10	μA
		V_{DS}=480V,　T_C=125℃	-	-	100	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	V_{DS}=0V,　V_{GS} =30V	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	V_{DS}=0V,　V_{GS} =-30V	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS} ,　I_D=250μA	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	V_{GS} =10V ,　I_D=1.0A 25℃	-	3.8	5.0	Ω
		V_{GS} =10V ,　I_D=1.0A 100℃	-	6.65	10.0	Ω
		V_{GS} =10V ,　I_D=1.0A 150℃	-	9.88	14	Ω
正向跨导 Forward Transconductance	g_{fs}	V_{DS} = 40V , I_D=1.0A（note 4）	-	2.45	-	S
动态特性 Dynamic Characteristics						
栅极电阻 Gate resistance	Rg	F=1.0MHz open drain	1.8	-	6.5	Ω
输入电容 Input capacitance	C_{iss}	V_{DS}=25V,V_{GS} =0V, f=1.0MHz	80	312	590	pF
输出电容 Output capacitance	C_{oss}		5	31	100	pF
反向传输电容 Reverse transfer capacitance	C_{rss}		0.2	3.1	10	pF

电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	t_d(on)	V_{DD}=300V,I_D=2.0A,R_G=25Ω （note 4，5）	-	16.7	45	ns
上升时间 Turn-On rise time	t_r		-	139	300	ns
延迟时间 Turn-Off delay time	t_d(off)		-	35.1	90	ns
下降时间 Turn-Off Fall time	t_f		-	12.2	43	ns
栅极电荷总量 Total Gate Charge	Q_g	V_{DS} =480V , I_D=2.0A V_{GS}=10V （note 4，5）	-	8.1	15	nC
栅－源电荷 Gate-Source charge	Q_{gs}		-	1.29	5	nC
栅－漏电荷 Gate-Drain charge	Q_{gd}		-	3.0	9	nC
漏－源二极管特性及最大额定值 **Drain-Source Diode Characteristics and Maximum Ratings**						
正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current	I_S		-	-	2.0	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}		-	-	8.0	A
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	V_{GS}=0V, I_S=2.0A	-	-	1.4	V
反向恢复时间 Reverse recovery time	t_{rr}	V_{GS}=0V, I_S=2.0A dI_F/dt=100A/μs (note 4)	-	247	600	ns
反向恢复电荷 Reverse recovery charge	Q_{rr}		-	1.04	3.0	μC

热特性 THERMAL CHARACTERISTIC

项 目 **Parameter**	符 号 **Symbol**	最大 **Max**				单 位 **Unit**
		JCS2N60 VC/RC/MFC	JCS2N60 TC	JCS2N60 FC	JCS2N60 CC	
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	2.87	-	2.85	2.32	℃/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	110	120	40.1		℃/W

注释：

1：脉冲宽度由最高结温限制

2：L=110mH, I_{AS}=2.0A, V_{DD}=50V, R_G=25 Ω,起始结温T_J=25℃

3：I_{SD} ≤2A,di/dt ≤300A/μs,VDD≤BV_{DSS},起始结温 T_J=25℃

4：脉冲测试：脉冲宽度≤300μs,占空比≤2%

5：基本与工作温度无关

Notes:

1：Pulse width limited by maximum junction temperature

2：L=110mH, I_{AS}=2.0A, V_{DD}=50V, R_G=25 Ω,Starting T_J=25℃

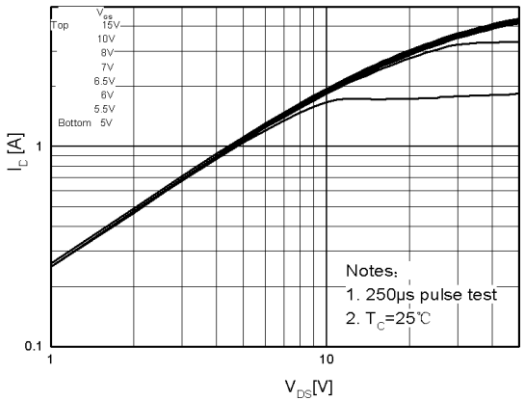
3：I_{SD} ≤2A,di/dt ≤300A/μs,VDD≤BV_{DSS}, Starting T_J=25℃

4：Pulse Test：Pulse Width ≤300μs,Duty Cycle≤2%

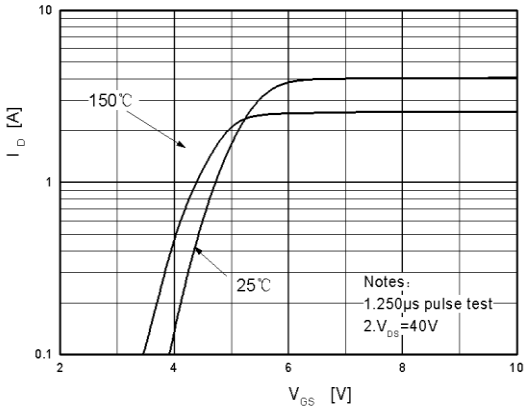
5：Essentially independent of operating temperature

特征曲线 ELECTRICAL CHARACTERISTICS (curves)

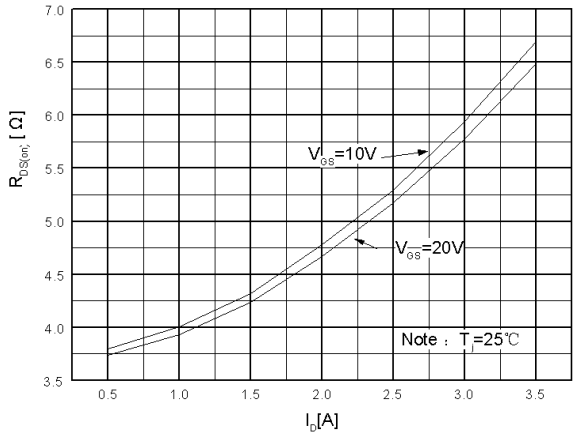
On-Region Characteristics



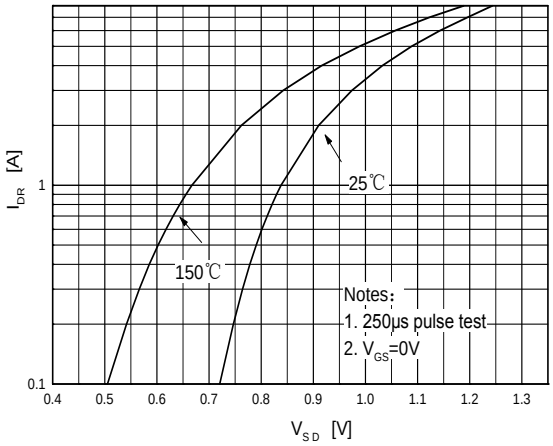
Transfer Characteristics



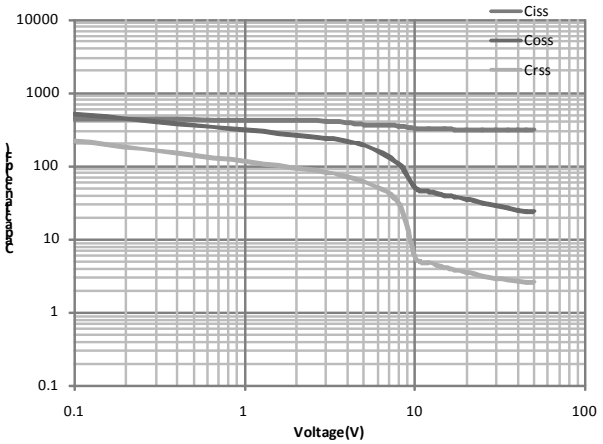
On-Resistance Variation vs. Drain Current and Gate Voltage



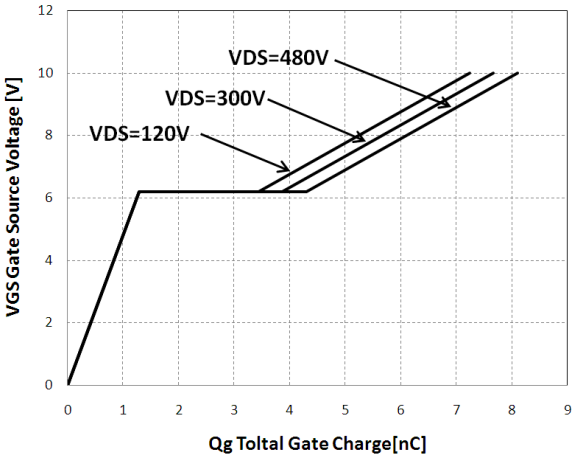
Body Diode Forward Voltage Variation vs. Source Current and Temperature



Capacitance Characteristics

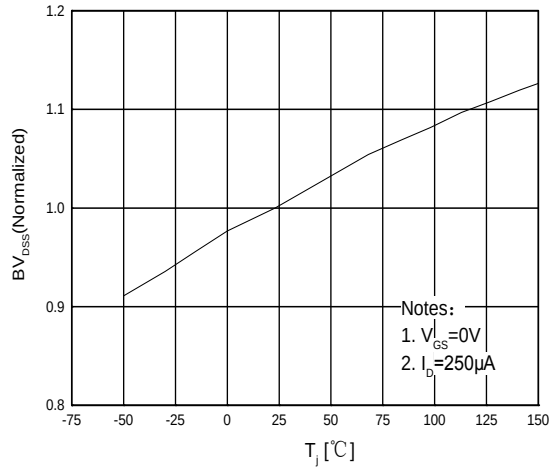


Gate Charge Characteristics

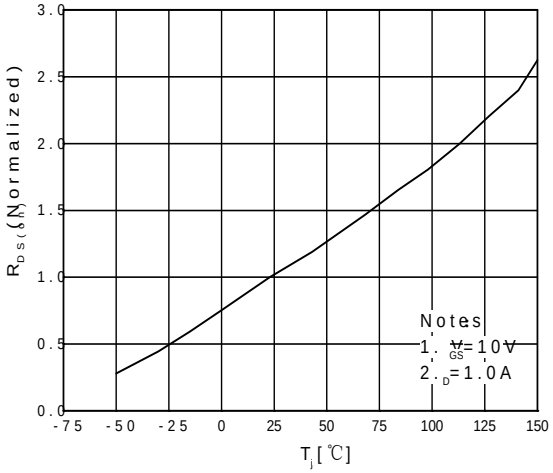


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

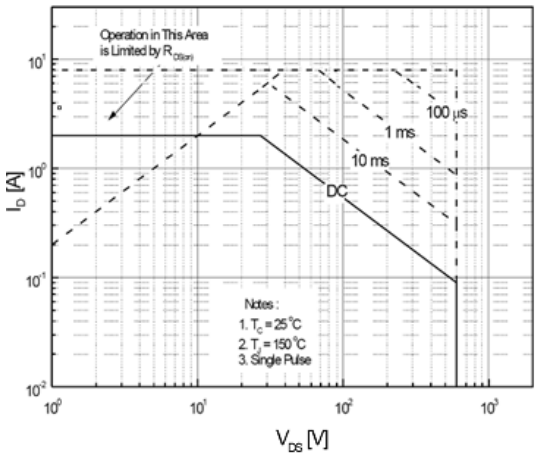
Breakdown Voltage Variation vs. Temperature



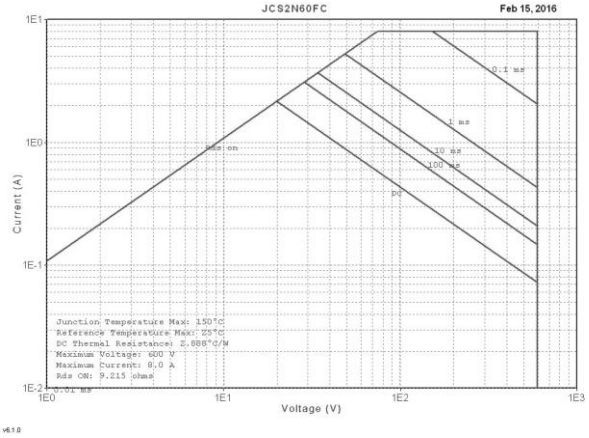
On-Resistance Variation vs. Temperature



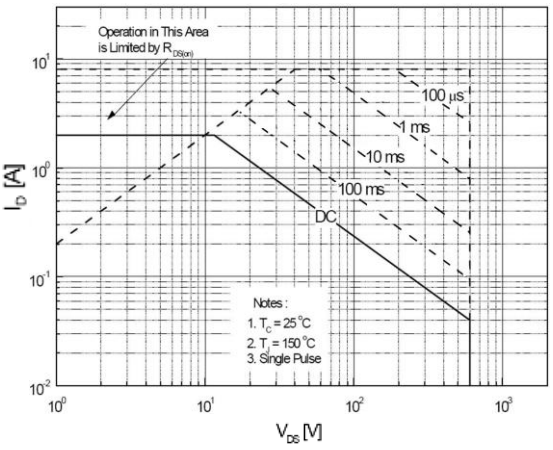
Maximum Safe Operating Area For JCS2N60VC/RC/CC/MFC



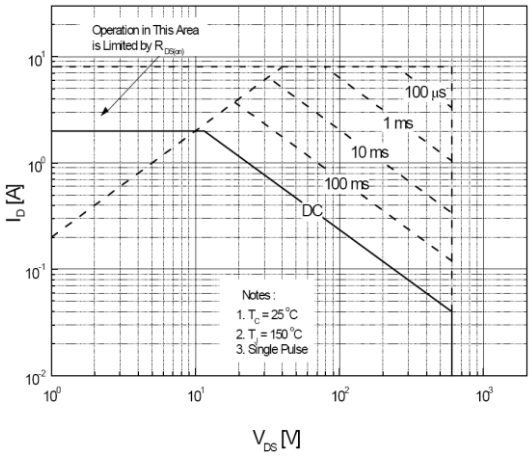
Maximum Safe Operating Area For JCS2N60FC(TO-220MF)



Maximum Safe Operating Area For JCS2N60FC(TO-220MF-K2)

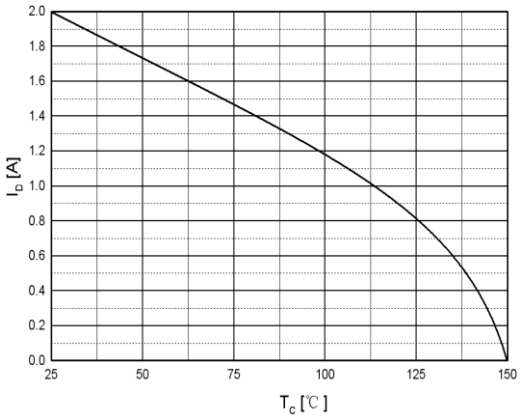


Maximum Safe Operating Area For JCS2N60TC

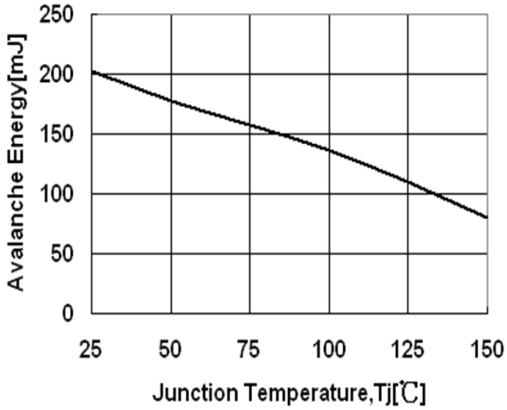


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

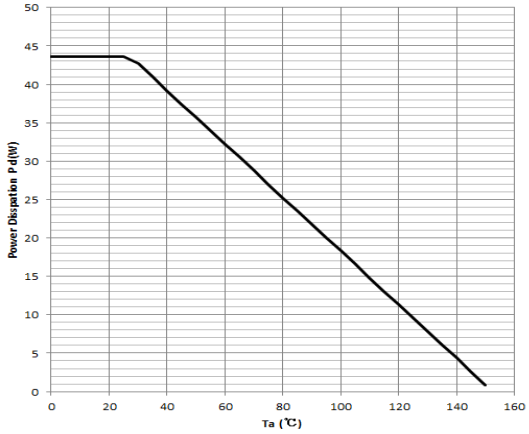
Maximum Drain Current vs. Case Temperature



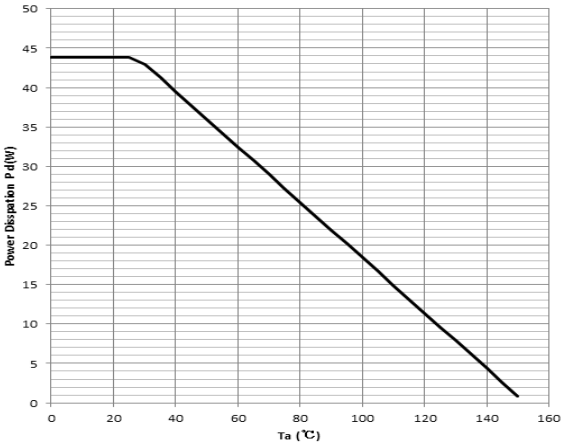
Avalanche Energy vs. Temperature



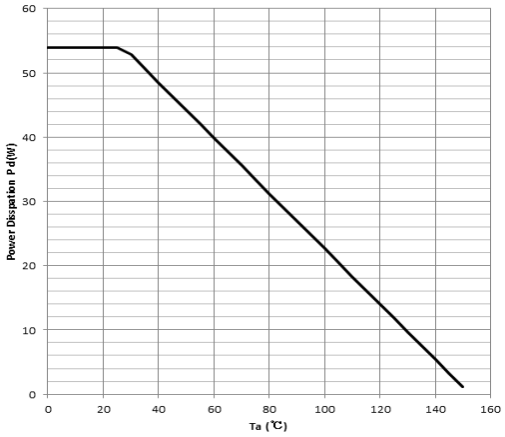
Power Disspation vs. Temperature(JCS2N60VC/RC/MFC)



Power Disspation vs. Temperature (JCS2N60FC/TO-220MF/K2)

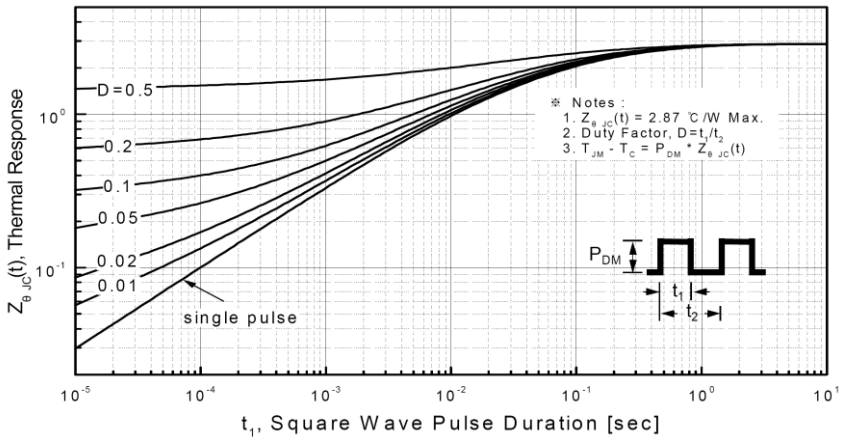


Power Disspation vs. Temperature(JCS2N60CC)

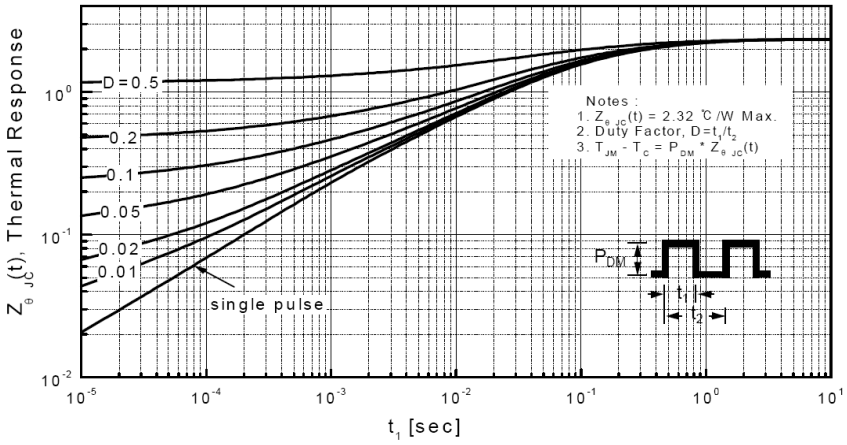


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Transient Thermal Response Curve For JCS2N60VC/RC/MFC

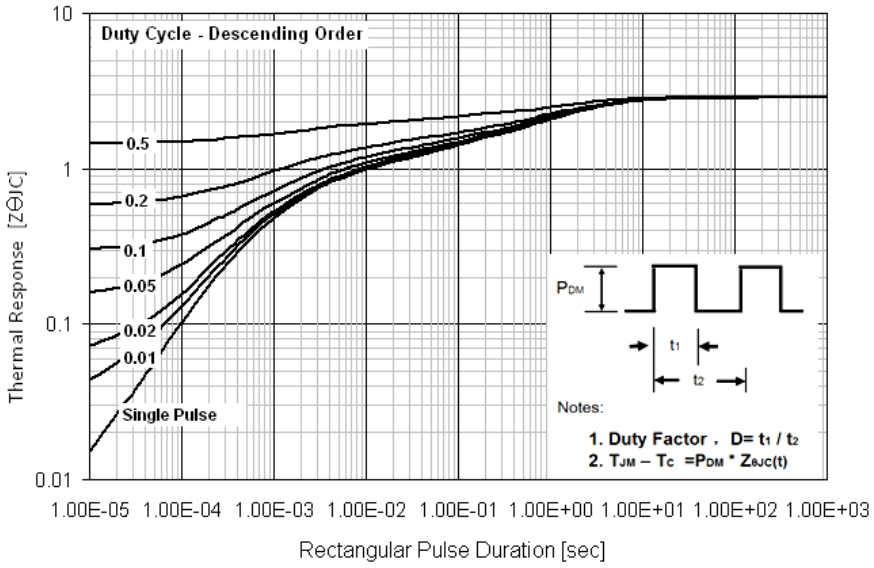


Transient Thermal Response Curve For JCS2N60CC

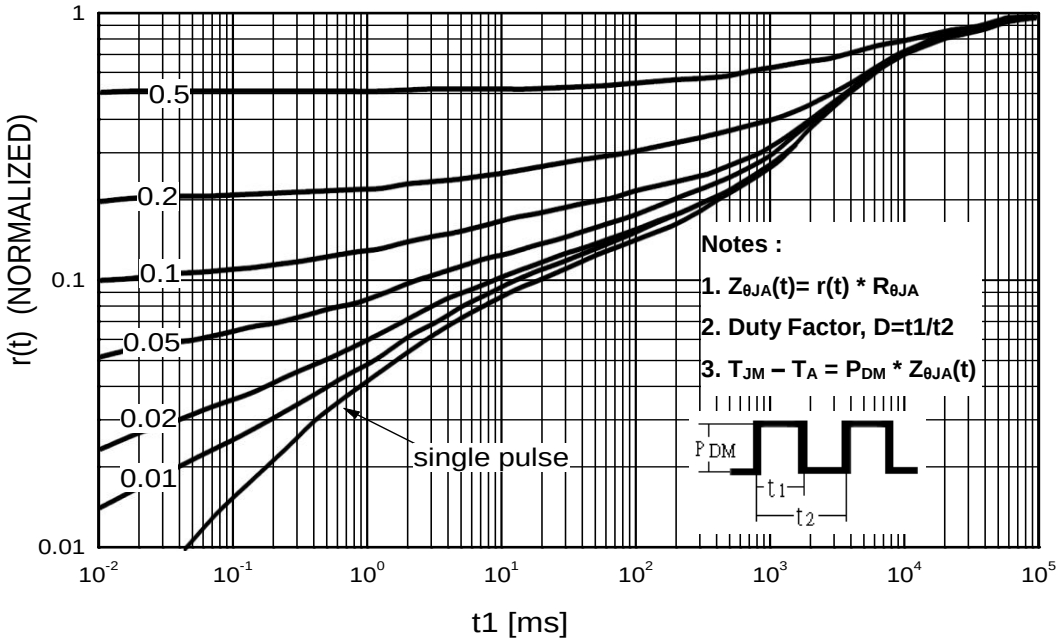


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Transient Thermal Response Curve For JCS2N60FC



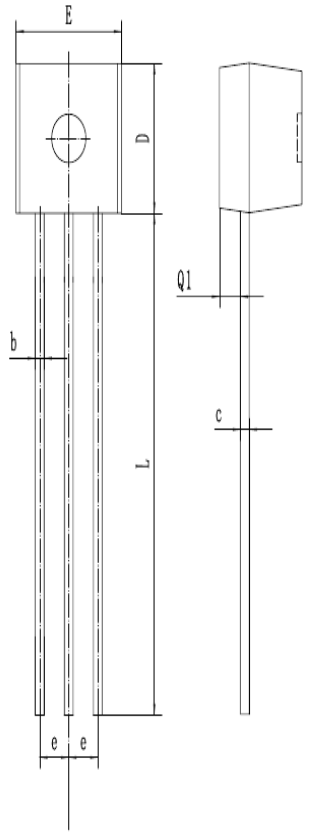
Transient Thermal Response Curve For JCS2N60TC



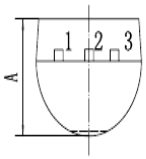
外形尺寸 PACKAGE MECHANICAL DATA

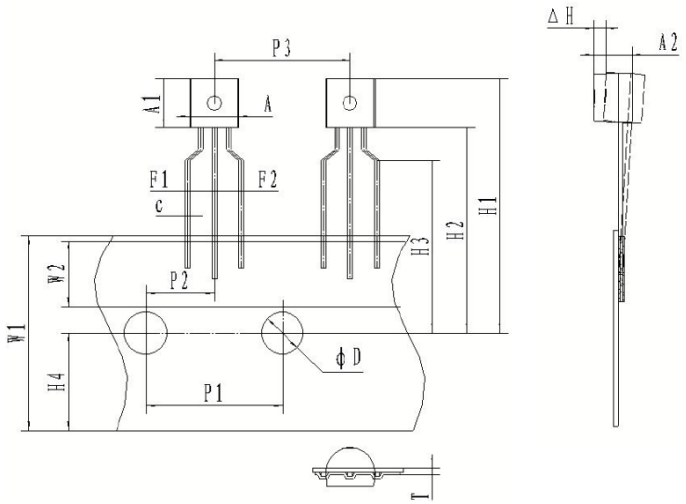
TO-92

单位 Unit：mm



符号 symbol	MIN	MAX
A	3.30	3.90
b	0.35	0.55
c	0.31	0.51
D	4.30	4.90
E	4.30	4.90
e	1.17	1.37
L	12.50	15.50
Q1	0.85	1.00



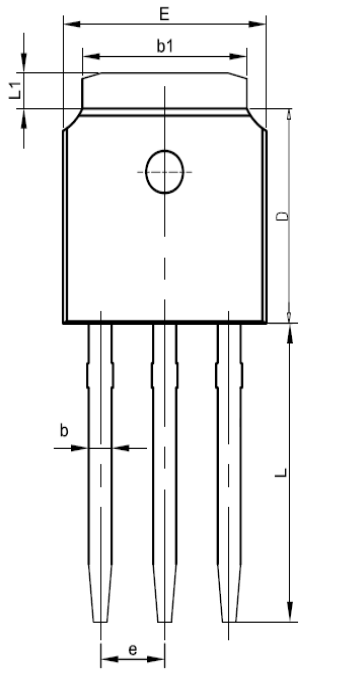


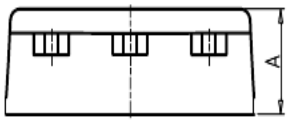
符号 symbol	min	max
A	4.5	4.7
A1	4.5	4.7
A2	3.5	3.7
c	TYP 0.45	
F1/F2	2.2	2.8
W1	17.5	18.5
W2	5.5	6.5
H1	22.0	27.0
H2	18.0	20.0
H3	15.0	17.0
H4	8.5	9.5
P1	12.5	12.9
P2	6.0	6.7
P3	12.5	12.9
T	0.40	0.45
ϕD	3.8	4.2
ΔH	0	1.0

外形尺寸 PACKAGE MECHANICAL DATA

IPAK

单位 Unit：mm



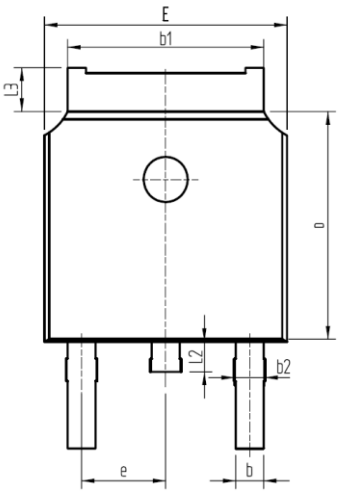


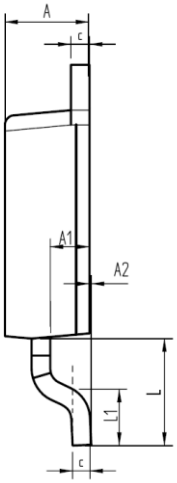
SYMBOL	MM	
	MIN	MAX
A	2.1	2.5
A1	0.87	1.27
b	0.63	0.93
b1	5.13	5.53
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
L	9.10	9.70
e	2.286BSC	
L1	0.82	1.22

外形尺寸 PACKAGE MECHANICAL DATA

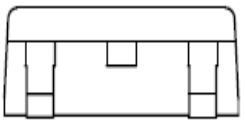
DPAK

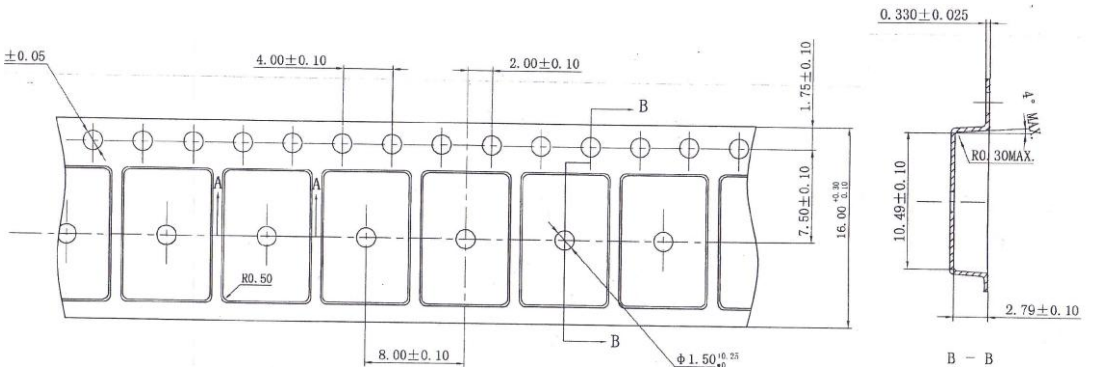
单位 Unit：mm

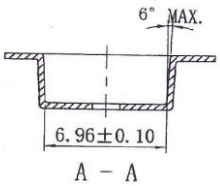




SYMBOL	mm	
	MIN	MAX
A	2.16	2.41
A1	0.97	1.17
A2	0.00	0.15
b	0.63	0.93
b1	5.13	5.53
b2	0.66	0.96
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30



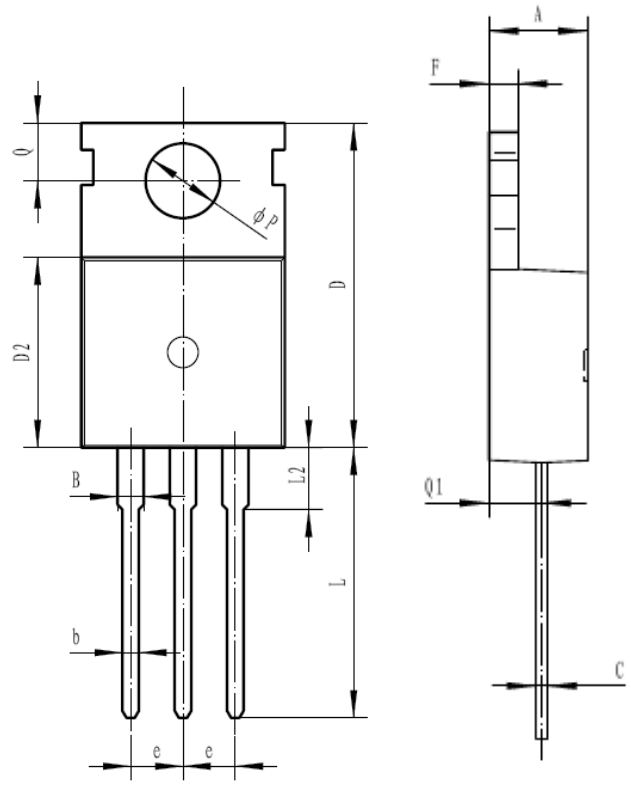


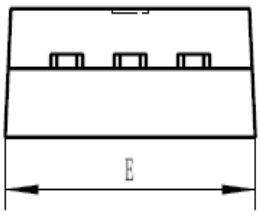


外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit：mm



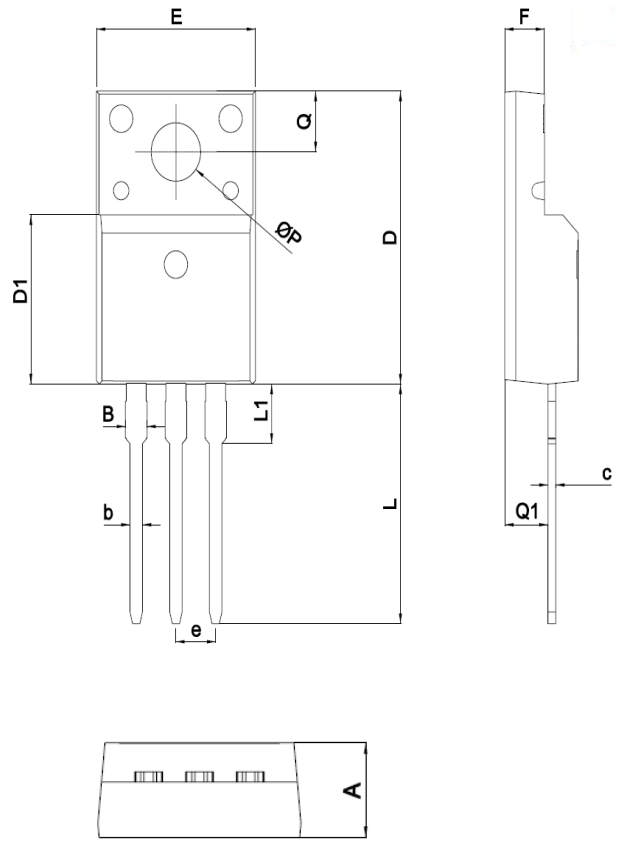


符号 symbol	MIN	MAX
A	4.30	4.70
B	1.22	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80

外形尺寸 **PACKAGE MECHANICAL DATA**

TO-220MF

单位 Unit：mm

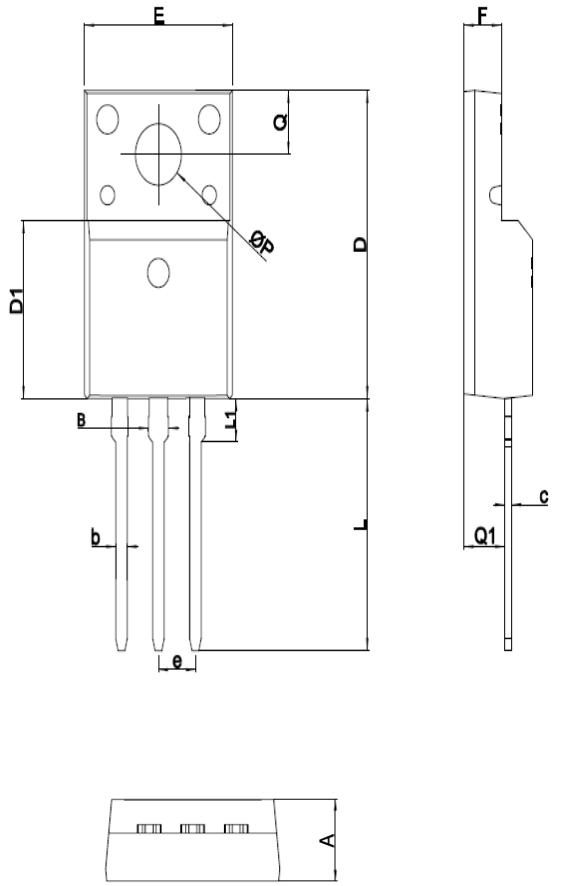


SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.47
b	0.7	0.9
c	0.45	0.60
D	15.67	16.07
D1	9.04	9.20
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.58	13.38
L1	3.13	3.33
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28

外形尺寸 **PACKAGE MECHANICAL DATA**

TO-220MF-K2

单位 Unit：mm

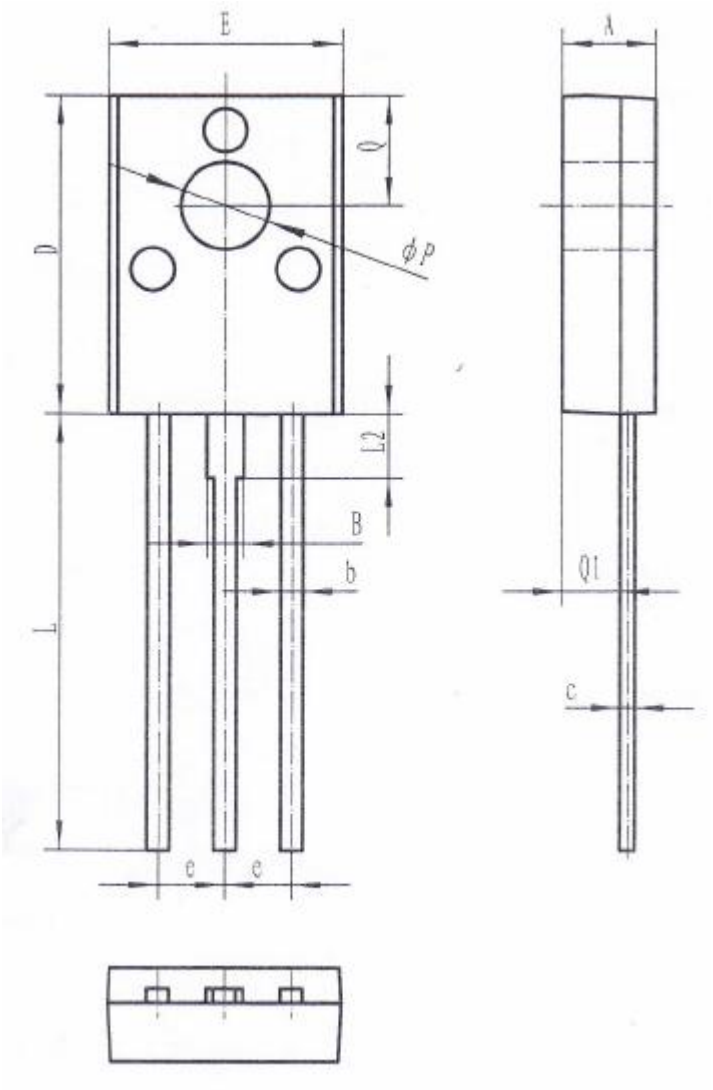


SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.27
b	0.59	0.79
c	0.45	0.60
D	15.67	16.07
D1	8.97	9.37
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.65	13.35
L1	1.80	2.20
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28

外形尺寸 **PACKAGE MECHANICAL DATA**

TO-126F

单位 Unit：mm



符号 symbol	MIN	MAX
A	3.10	3.30
B	1.22	1.47
b	0.60	0.90
c	0.45	0.70
D	10.50	11.20
E	7.50	8.50
e	2.29 TYP	
L	15.00	16.00
L2	2.10	2.30
Q	3.60	4.00
Q1	1.80	2.20
P	2.95	3.15

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联系方式

吉林华微电子股份有限公司

公司地址：吉林省吉林市深圳街 99 号

邮编：132013
总机：86-432-64678411
传真：86-432-64665812
网址：www.hwdz.com.cn

市场营销部
地址：吉林省吉林市深圳街 99 号

邮编：132013
电话： 86-432-64675588
64675688
64678411
传真: 86-432-64671533

CONTACT

JILIN SINO-MICROELECTRONICS CO., LTD.

ADD: No.99 Shenzhen Street, Jilin City, Jilin Province, China.
Post Code: 132013
Tel： 86-432-64678411
Fax：86-432-64665812
Web Site：www.hwdz.com.cn

MARKET DEPARTMENT
ADD: No.99 Shenzhen Street, Jilin City, Jilin Province, China.
Post Code: 132013
Tel: 86-432-64675588
64675688
64678411
Fax: 86-432-64671533